Diode Module

STARPOWER

SEMICONDUCTOR

FRED

FD400CCS10D1S

Molding Type Module

100V/400A in one-package



General Description

STARPOWER Diode Power Module provides low forward voltage as well as low reverse recovery loss. They are designed for the applications such as SMPS.

Features

- Fast soft diode
- Low forward voltage drop
- Small temperature coefficient
- Low reverse recovery losses
- High ruggedness
- Low inductance

1 • Equivalent Circuit Schematic

Cu Plate

Typical Applications

- SMPS
- PFC
- Electric welders
- DC choppers

Symbol	Description	FD400CCS10D1S	Units	
V _{RRM}	Repetitive Peak Reverse Voltage	100	V	
V _{RSM}	Non-repetitive Peak Reverse Voltage	100	V	
I _{FAV}	Average Forward Current T _C =100°C,Diode	200	А	
	T_{C} =100 °C ,Module	400	A	
I _{FSM}	Surge Forward Current $V_R=0V_{,t_p}=10m_{,t_j}=25^{\circ}C$	2000	А	
	$V_R=0V, t_p=8.3 \text{ms}, T_j=25 \text{°C}$	2200		
I ² t	I^2 t-value V _R =0V,t _p =10ms,T _j =25°C	20000	A ² s	
	$V_R=0V, t_p=8.3 \text{ms}, T_j=25^{\circ}\text{C}$	20166		
P _D	Maximum Power Dissipation @ T _j =175°C	932	W	
Tj	Junction Temperature	-40 to +175	°C	
T _{STG}	Storage Temperature Range	-40 to +125	°C	
М	Terminal Connection Torque, Screw M6	3.0 to 4.7		
	Mounting Torque, Screw M4	1.0 to 1.5	N.m	
	Mounting Torque, Screw M6	3.0 to 4.7		

Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

Electrical Characteristics of Diode $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
$V_{\rm F}$	Diode Forward	I _F =200A	T _i =25℃		0.83	1.03	V
	Voltage		T _j =125℃		0.80	1.00	v
I _R	Diode Reverse	V _R =V _{RRM}	T _j =25℃			0.5	mA
	Current		T _j =125℃			1.0	
t _{rr}	Reverse Recovery	$I_F=200A \\ V_R=50V \\ di/dt=-200A/\mu s$	T _i =25℃		55		ns
	Time		T _i =125℃		75		
I _{RM}	Peak Reverse		T _i =25℃		40		٨
	Recovery Current		T _i =125℃		50		A

Thermal Characteristics

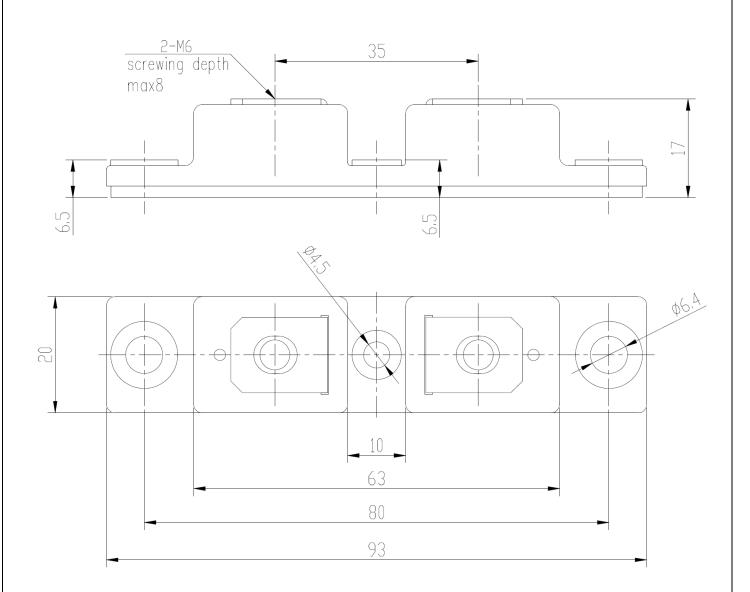
Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case		0.161	K/W
$R_{\theta CS}$	Case-to-Sink (Conductive grease applied)	0.06		K/W
Weight	Weight of Module	70		g

FD400CCS10D1S

Diode Module

Package Dimensions

Dimensions in Millimeters



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